



80V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI1012-8 (TOLL)

Product Summary

| BV _{DSS} | Rds(on) Max | I⊳ Тс = +25°С |
|-------------------|-------------------------------|------------------|
| 80V | 1.7mΩ @ V _{GS} = 10V | 270A |

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Motor Control
- DC-DC Converters
- Power Management

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH8001STLWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

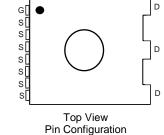
Mechanical Data

- Case: POWERDI[®]1012-8 (TOLL)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.388 grams (Approximate)

S

Internal Schematic





Ordering Information (Note 4)

| Case | Packaging | | | | |
|---------------|------------------|--|--|--|--|
| POWERDI1012-8 | 1500/Tape & Reel | | | | |
| | | | | | |

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



] ||= Manufacturer's Marking
 TH8001STL = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 21 = 2021)
 WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

DMTH8001STLWQ Document number: DS43141 Rev. 3 - 2



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|---|-------|------------|---|
| Drain-Source Voltage | Vdss | 80 | V | |
| Gate-Source Voltage | Vgss | ±20 | V | |
| Continuous Drain Current (Note 6) V _{GS} = 10V | T _C = +25°C T _C = +100°C | ID | 270 190 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | Ідм | 1080 | А | |
| Maximum Continuous Body Diode Forward Current (Note 6) | ls | 270 | А | |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | lsм | 1080 | А | |
| Avalanche Current, L=1mH | las | 47 | А | |
| Avalanche Energy, L=1mH | Eas | 1104 | mJ | |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|------------------------|------------------|-------------|------|
| Total Power Dissipation (Note 5) | T _A = +25°C | PD | 6 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{0JA} | 25 | °C/W |
| Total Power Dissipation (Note 6) | T _C = +25°C | PD | 250 | W |
| Thermal Resistance, Junction to Case (Note 6) | | Rejc | 0.6 | °C/W |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +175 | °C |

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Мах | Unit | Test Condition | |
|-----------------------------------|---------------------|-----|------|------|------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | ÷ | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 80 | — | — | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | IDSS | _ | — | 1 | μA | $V_{DS} = 64V, V_{GS} = 0V$ | |
| Gate-Source Leakage | Igss | _ | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 2 | — | 4 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 1.3 | 1.7 | mΩ | $V_{GS} = 10V, I_D = 30A$ | |
| Diode Forward Voltage | V _{SD} | — | 0.8 | 1.2 | V | $V_{GS} = 0V, I_{S} = 30A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | _ | 8894 | | | V _{DS} = 50V, V _{GS} = 0V f = 1MHz | |
| Output Capacitance | Coss | _ | 2273 | — | pF | | |
| Reverse Transfer Capacitance | Crss | — | 34 | — | | | |
| Gate Resistance | Rg | _ | 2.6 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge | QG | _ | 138 | — | | N/ 50X/1 00A | |
| Gate-Source Charge | QGS | — | 36 | — | nC | $V_{DD} = 50V, I_D = 30A,$ $V_{GS} = 10V$ | |
| Gate-Drain Charge | Q _{GD} | — | 36 | — | | | |
| Turn-On Delay Time | tD(ON) | _ | 24 | _ | | | |
| Turn-On Rise Time | tR | _ | 60 | _ | | $\label{eq:VDD} \begin{split} V_{DD} &= 50V, \ V_{GS} = 10V, \\ I_D &= 30A, \ R_G = 4.7\Omega \end{split}$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 108 | | ns | | |
| Turn-Off Fall Time | tF | | 72 | | | | |
| Reverse Recovery Time | trr | | 94 | | ns | | |
| Reverse Recovery Charge | Q _{RR} | _ | 291 | _ | nC | I _F = 25A, di/dt = 100A/μs | |

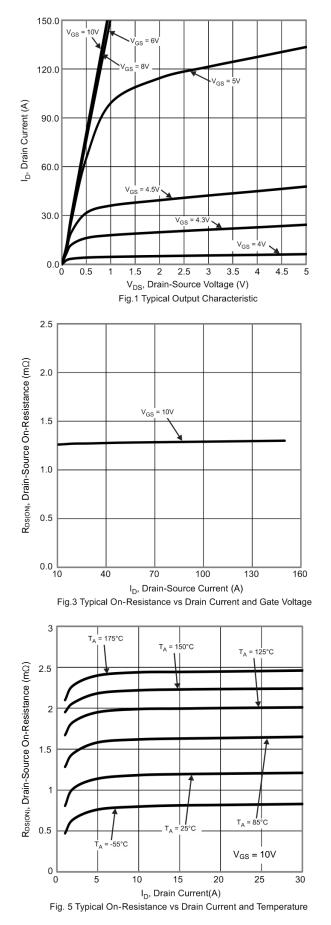
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

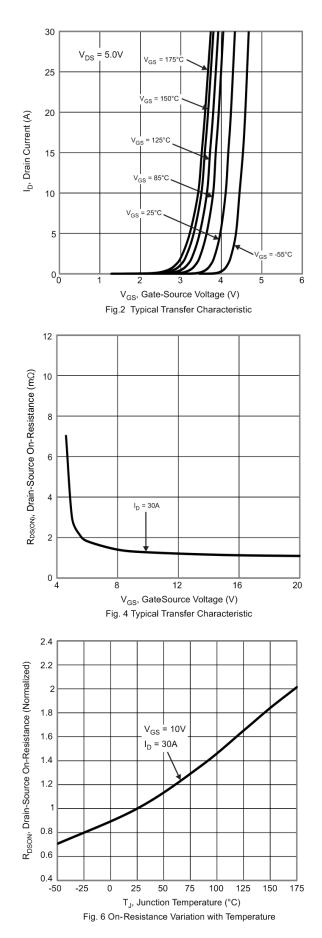
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



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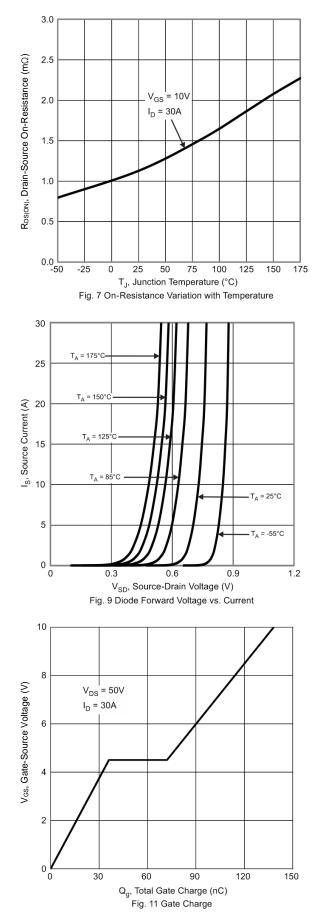


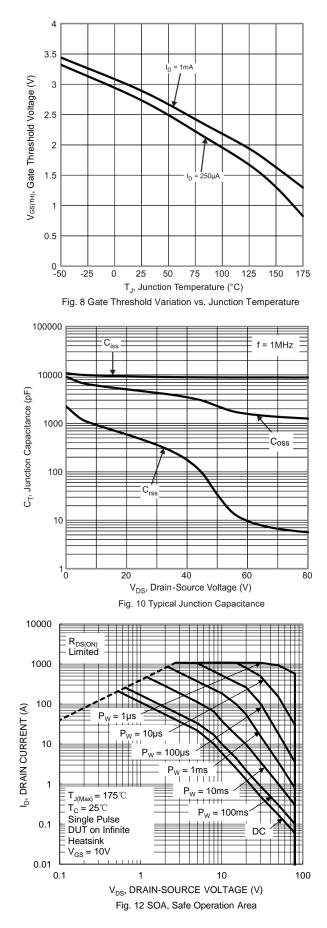


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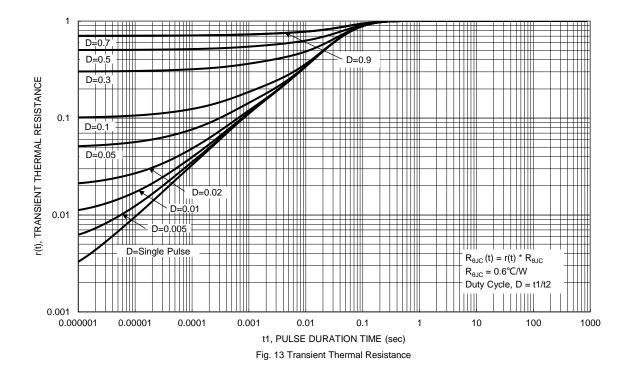
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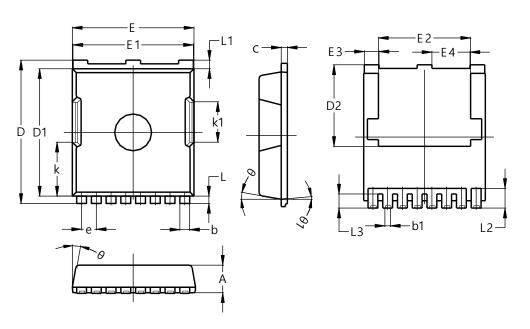




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

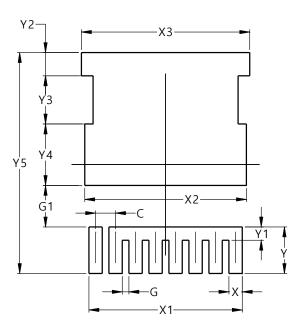
POWERDI1012-8



| | POWERDI1012-8 | | | | | |
|-----|---------------|-----------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 2.20 | 2.40 | 2.30 | | | |
| b | 0.70 | 0.90 | 0.80 | | | |
| b1 | 0.42 | 0.50 | 0.45 | | | |
| С | 0.40 | 0.60 | 0.50 | | | |
| D | 11.48 | 11.88 | 11.68 | | | |
| D1 | 10.23 | 10.53 | 10.38 | | | |
| D2 | 6.45 | 6.85 | 6.65 | | | |
| E | 9.70 | 10.10 | 9.90 | | | |
| E1 | 9.70 | 9.90 | 9.80 | | | |
| E2 | 7.00 | 8.00 | 7.50 | | | |
| E3 | 1.10 | 1.30 | 1.20 | | | |
| E4 | 3.00 | 3.20 | 3.10 | | | |
| е | 1.20 BSC | | | | | |
| k | 4.39 REF | | | | | |
| k1 | | 3.30 REF | - | | | |
| L | 0.50 | 0.70 | 0.60 | | | |
| L1 | 0.50 | 0.90 | 0.70 | | | |
| L2 | 1.40 | 1.80 | 1.60 | | | |
| L3 | 1.00 | 1.30 | 1.15 | | | |
| θ | 0° | 15° | 10º | | | |
| θ1 | 0° | 10º | 5° | | | |
| All | Dimens | ions in r | nm | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



POWERDI1012-8

| Dimensions | Value (in mm) | | |
|------------|------------------|--|--|
| С | 1.200 | | |
| G | 0.400 | | |
| G1 | 2.500 | | |
| Х | 0.800 | | |
| X1 | 9.200 | | |
| X2 | 9.700 | | |
| Х3 | 10.100 | | |
| Y | 2.800 | | |
| Y1 | 0.800 | | |
| Y2 | 1.400 | | |
| Y3 | 2.900 | | |
| Y4 | 3.700 | | |
| Y5 | 13.300 | | |



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